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APPLICANTS

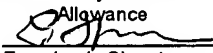
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**\*\* CONTINUING DATA \*\*\*\*\***  
 This application is a DIV of 09/989,112 11/21/2001 PAT 6,670,677

**\*\* FOREIGN APPLICATIONS \*\*\*\*\***  
 REPUBLIC OF KOREA 2001-28008 05/22/2001

IF REQUIRED, FOREIGN FILING LICENSE GRANTED  
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Foreign Priority claimed 35 USC 119 (a-d) conditions met Verified and Acknowledged	<input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance  Examiner's Signature	STATE OR COUNTRY KOREA, REPUBLIC OF	SHEETS DRAWING 8	TOTAL CLAIMS 25	INDEPENDENT CLAIMS 3
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TITLE  
 SOI substrate having an etch stop layer, and fabrication method thereof, SOI integrated circuit fabricated thereon, and method of fabricating SOI integrated circuit using the same

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